

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE2312 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a battery protection or in other switching application.

General Features

• $V_{DS} = 20V, I_D = 4.5A$

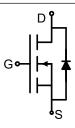
 $R_{DS(ON)}$ < 40m Ω @ V_{GS} =2.5V

 $R_{DS(ON)}$ < 25m Ω @ V_{GS} =4.5V

- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- Battery protection
- Load switch
- Power management



Schematic diagram



Marking and pin assignment



SOT-23 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2312 \$₹	NCE2312	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage	V _G s	±12	V		
Continuous Drain Current	T _A =25℃		4.5	^	
Continuous Drain Current	T _A =70℃	I _D	3.6	Α	
Drain Current-Pulsed (Note 1)	I _{DM}	15	Α		
Maximum Power Dissipation	P _D	1.25	W		
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55 To 150	$^{\circ}$	

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	100	°C/W

Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	20	-	-	V



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NCE2312

V _{GS} =±12V,V _{DS} =0V V _{DS} =V _{GS} ,I _D =250μA V _{GS} =2.5V, I _D =2.5A V _{GS} =4.5V, I _D =2.5A V _{DS} =10V,I _D =2.5A V _{DS} =10V,V _{GS} =0V, F=1.0MHz	- 0.5	0.65 19 16 10 637 133 124	±100 1.0 40 25 -	nA V mΩ S PF
V _{GS} =2.5V, I _D =2.5A V _{GS} =4.5V, I _D =2.5A V _{DS} =10V,I _D =2.5A V _{DS} =10V,V _{GS} =0V,		19 16 10 637 133	40 25 -	mΩ mΩ S
V _{GS} =2.5V, I _D =2.5A V _{GS} =4.5V, I _D =2.5A V _{DS} =10V,I _D =2.5A V _{DS} =10V,V _{GS} =0V,		19 16 10 637 133	40 25 -	mΩ mΩ S
V _{GS} =4.5V, I _D =2.5A V _{DS} =10V,I _D =2.5A V _{DS} =10V,V _{GS} =0V,	-	16 10 637 133	25	mΩ S
V _{DS} =10V,I _D =2.5A V _{DS} =10V,V _{GS} =0V,	-	10 637 133	-	S
V _{DS} =10V,V _{GS} =0V,	-	637		PF
, , , ,	-	133	-	
, , , ,	-	133		
, , , ,			-	PF
r-1.0ivinz	-	124		
			-	PF
		11	-	nS
V _{DD} =10V,I _D =2.5A	-	30	-	nS
V_{GS} =4.5V, R_{GEN} =6 Ω		35	-	nS
		10	-	nS
	-	11.1	15	nC
V _{DS} =10V,I _D =2.5A,V _{GS} =4.5V	-	1.1	-	nC
100 111,10 =111,100 1111	_	3.4	-	nC
150 111,15 2101,100 1101	1			
	<u> </u>			
V _{GS} =0V,I _S =2.5A	-	-	1.2	V
		-	- 3.4	- 3.4 -

Notes:

- 1. Repetitive rating: pulse width limited by maximum junction temperature.
- **2.** Surface mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse test: pulse width ≤ 300µs, duty cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

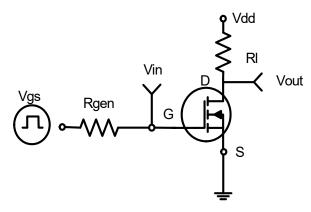


Figure 1:Switching Test Circuit

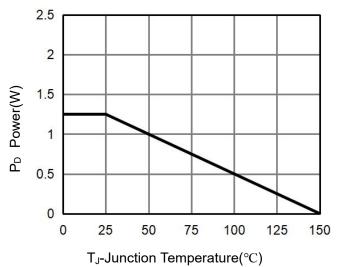


Figure 3 Power Dissipation

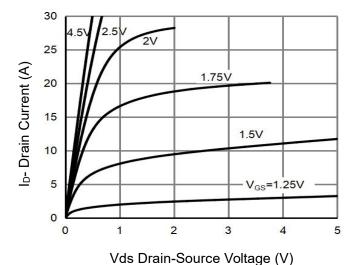


Figure 5 Output Characteristics

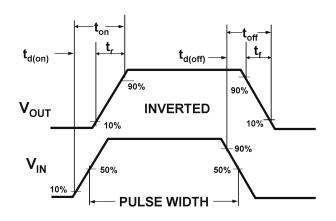


Figure 2:Switching Waveforms

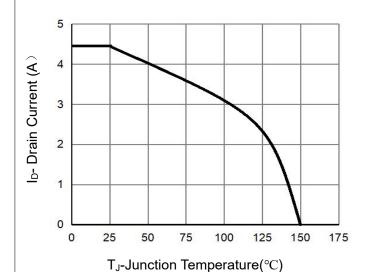


Figure 4 Drain Current

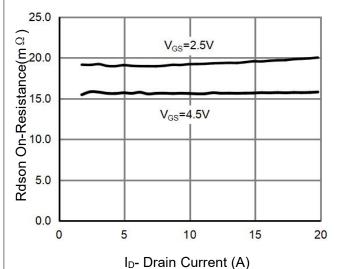


Figure 6 Drain-Source On-Resistance



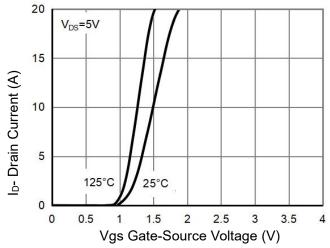
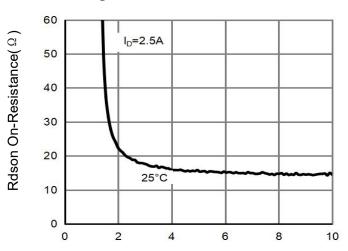
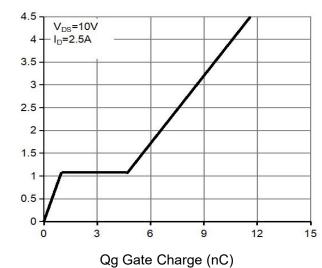


Figure 7 Transfer Characteristics



Vgs Gate-Source Voltage (V) Figure 9 Rdson vs. Vgs



Vgs Gate-Source Voltage (V)

Figure 11 Gate Charge

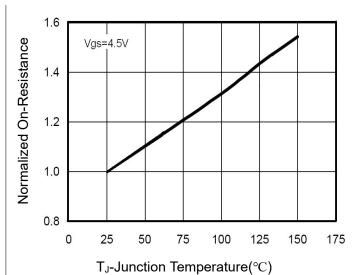
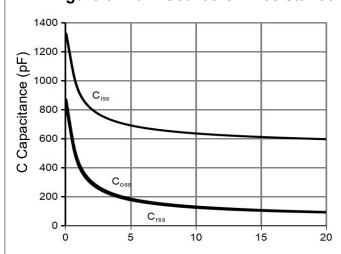
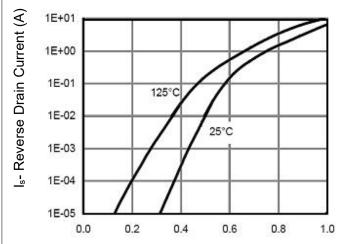


Figure 8 Drain-Source On-Resistance



Vds Drain-Source Voltage (V)

Figure 10 Capacitance vs Vds



Vsd Source-Drain Voltage (V)

Figure 12 Source- Drain Diode Forward



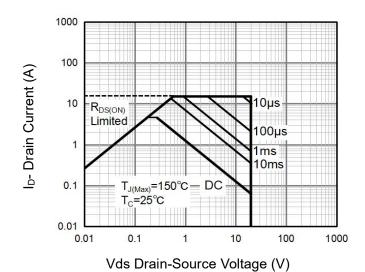


Figure 13 Safe Operation Area

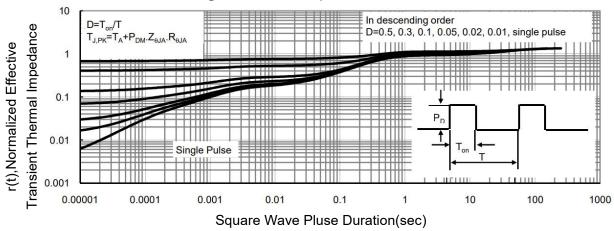
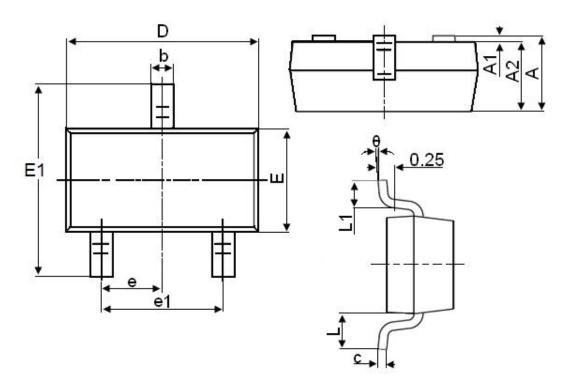


Figure 14 Normalized Maximum Transient Thermal Impedance



SOT-23 Package Information



Cumbal	Dimensions in Millimeters				
Symbol	MIN.	MAX.			
А	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
С	0.080	0.150			
D	2.800	3.000			
Е	1.200	1.400			
E1	2.250	2.550			
е		0.950TYP			
e1	1.800	2.000			
L		0.550REF			
L1	0.300	0.500			
θ	0°	8°			

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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